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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Application Number	Unassigned 10/512022
		Filing Date	October 19, 2004
		First Named Inventor	Tetsuhiro et al.
		Art Unit	Unassigned 1722
		Examiner Name	Unassigned Hiteshew
Sheet	1	of	1
		Attorney Docket Number	93120

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear
F.H.		4,002,523	01/11/1977	Dyer	→
F.H.		5,911,823	06/15/1999	Sonoda et al.	—

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document Country Code ² -Number ³ -Kind Code ⁴ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁵
F.H.		JP 63123893	05/27/1988	Shoichi et al.		Abstract
F.H.		JP 03080184	04/04/1991	NEC Corporation		Abstract
F.H.		JP 57-017494	01/29/1982	Toshiba Corporation		Abstract
F.H.		JP 09-165298	06/24/1997	Koji et al.		Abstract

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁵
F.H.		Murthy et al.; "Growth of Dislocation-Free Silicon Crystals in the (110) Direction for Use as Neutron Monochromators," <i>Journal of Crystal Growth</i> , Vol. 52, (1981), pp. 391-395.	
F.H.		Hoshikawa et al.; "Dislocation-Free Czochralski Silicon Crystal Growth without the Dislocation-Elimination-Necking Process," <i>Japan Journal of Applied Phys.</i> , Vol. 38 (1999) pp. L1369-L1371.	

Examiner Signature		Date Considered	8/2/04
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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